



# BAP55LX

Silicon PIN diode

Rev. 5 — 12 February 2019

Product data sheet

## 1 Product profile

---

### 1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

### 1.2 Features and benefits

- High-speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

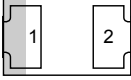

### 1.3 Applications

- RF attenuators and switches



## 2 Pinning information

Table 1. Discrete pinning

Pin	Description		Simplified outline	Symbol
1	cathode	[1]	 <p>Transparent top view</p>	 <i>sym006</i>
2	anode			

[1] The marking bar indicates the cathode.

## 3 Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BAP55LX	DFN1006D-2	leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm	SOD882D

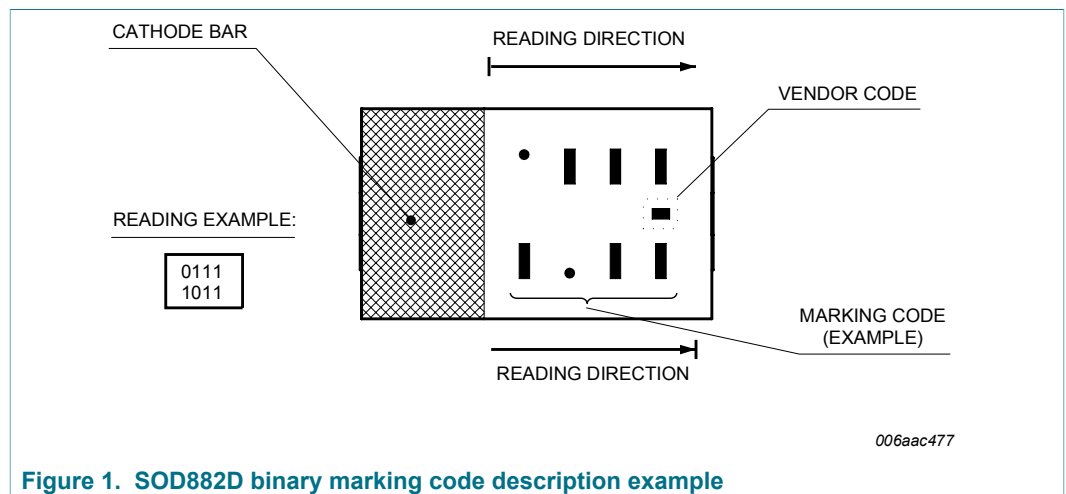
## 4 Marking

Table 3. Marking codes

Type number	Marking code <sup>[1]</sup>
BAP55LX	1111 1101

[1] For SOD882D binary marking code description (see [Figure 1](#)).

### 4.1 Binary marking code description



## 5 Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	50	V
$I_F$	forward current		-	100	mA
$P_{tot}$	total power dissipation	$T_{sp} \leq 90\text{ °C}$	-	135	mW
$T_{stg}$	storage temperature		-65	+150	°C
$T_j$	junction temperature		-65	+150	°C

## 6 Thermal characteristics

**Table 5. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		78	K/W

## 7 Characteristics

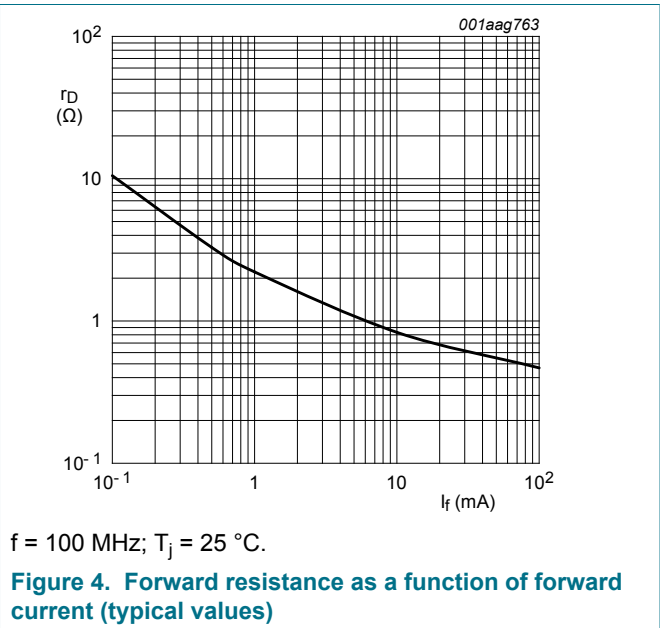
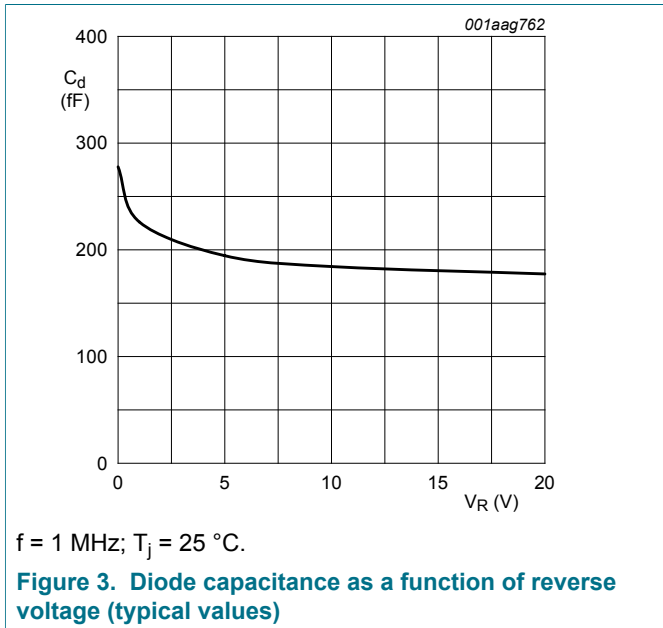
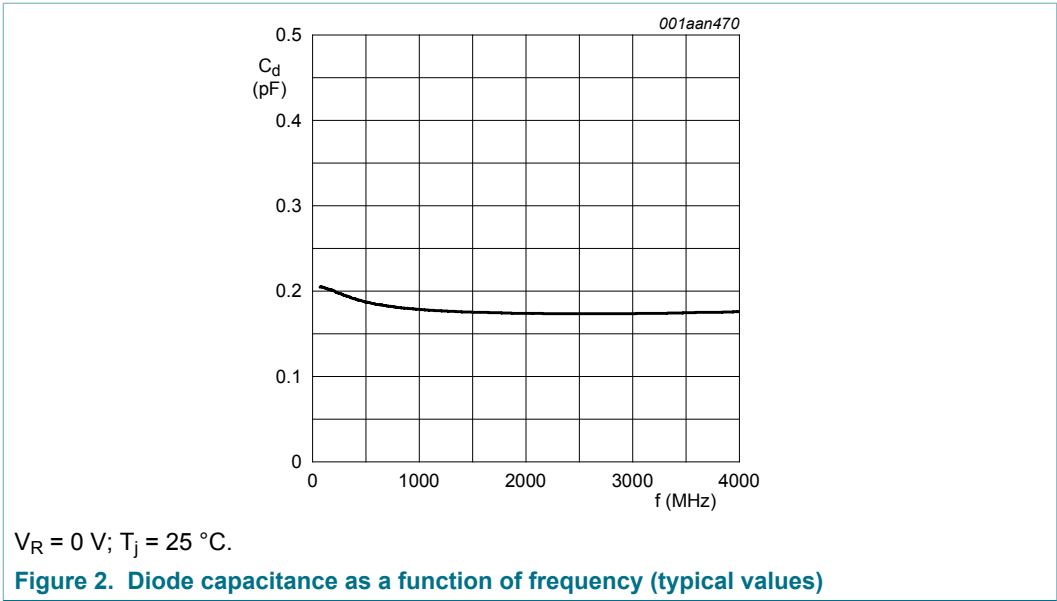
**Table 6. Characteristics**

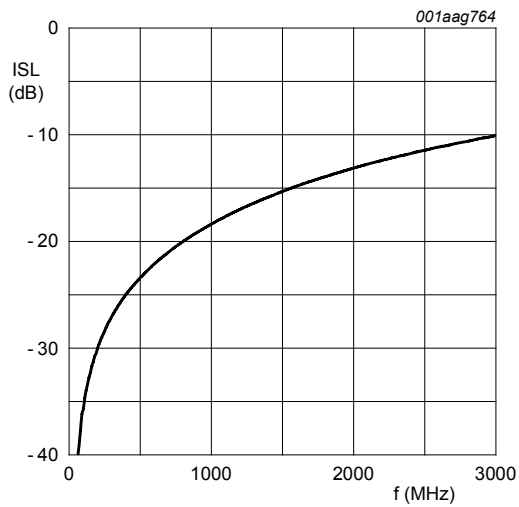
$T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_F$	forward voltage	$I_F = 50\text{ mA}$	-	0.95	1.1	V
$I_R$	reverse current	$V_R = 20\text{ V}$	-	-	10	nA
		$V_R = 50\text{ V}$	-	-	100	nA
$C_d$	diode capacitance	f = 1 MHz (see <a href="#">Figure 3</a> )				
		$V_R = 0\text{ V}$	-	0.28	-	pF
		$V_R = 1\text{ V}$	-	0.23	-	pF
		$V_R = 20\text{ V}$	-	0.18	0.28	pF
$r_D$	diode forward resistance	f = 100 MHz (see <a href="#">Figure 4</a> )				
		$I_F = 0.5\text{ mA}$	-	3.3	4.5	$\Omega$
		$I_F = 1\text{ mA}$	-	2.2	3.3	$\Omega$
		$I_F = 10\text{ mA}$	-	0.8	1.2	$\Omega$
		$I_F = 100\text{ mA}$	-	0.5	0.8	$\Omega$
ISL	isolation	$V_R = 0\text{ V}$ (see <a href="#">Figure 5</a> )				
		f = 900 MHz	-	19	-	dB
		f = 1800 MHz	-	14	-	dB
		f = 2450 MHz	-	12	-	dB
$L_{ins}$	insertion loss	(See <a href="#">Figure 6</a> )				
		$I_F = 0.5\text{ mA}$				
		f = 900 MHz	-	0.24	-	dB
		f = 1800 MHz	-	0.25	-	dB
		f = 2450 MHz	-	0.26	-	dB
		$I_F = 1\text{ mA}$				
		f = 900 MHz	-	0.17	-	dB
		f = 1800 MHz	-	0.18	-	dB
		f = 2450 MHz	-	0.19	-	dB
		$I_F = 10\text{ mA}$ ;				
		f = 900 MHz	-	0.08	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.10	-	dB
		$I_F = 100\text{ mA}$ ;				
		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.08	-	dB

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\tau_L$	charge carrier life time	when switched from $I_F = 10 \text{ mA}$ to $I_R = 6 \text{ mA}$ ; $R_L = 100 \text{ }\Omega$ ; measured at $I_R = 3 \text{ mA}$	0.225	0.27	-	$\mu\text{s}$
$L_S$	series inductance	$I_F = 100 \text{ mA}$ ; $f = 100 \text{ MHz}$	-	0.4	-	nH

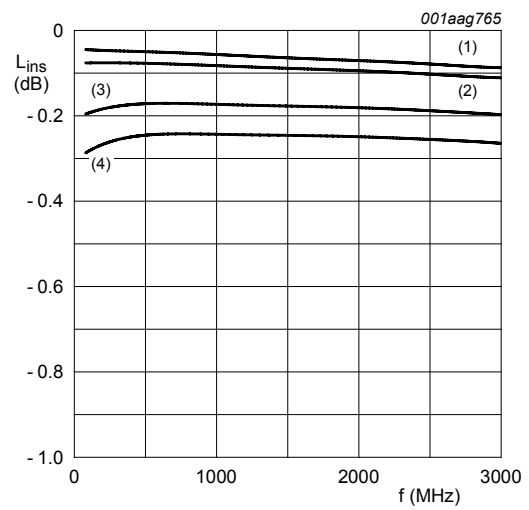
**7.1 Graphical data**





$T_{amb} = 25\text{ }^{\circ}\text{C}$   
 Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit

**Figure 5. Isolation of the diode as a function of frequency (typical values)**



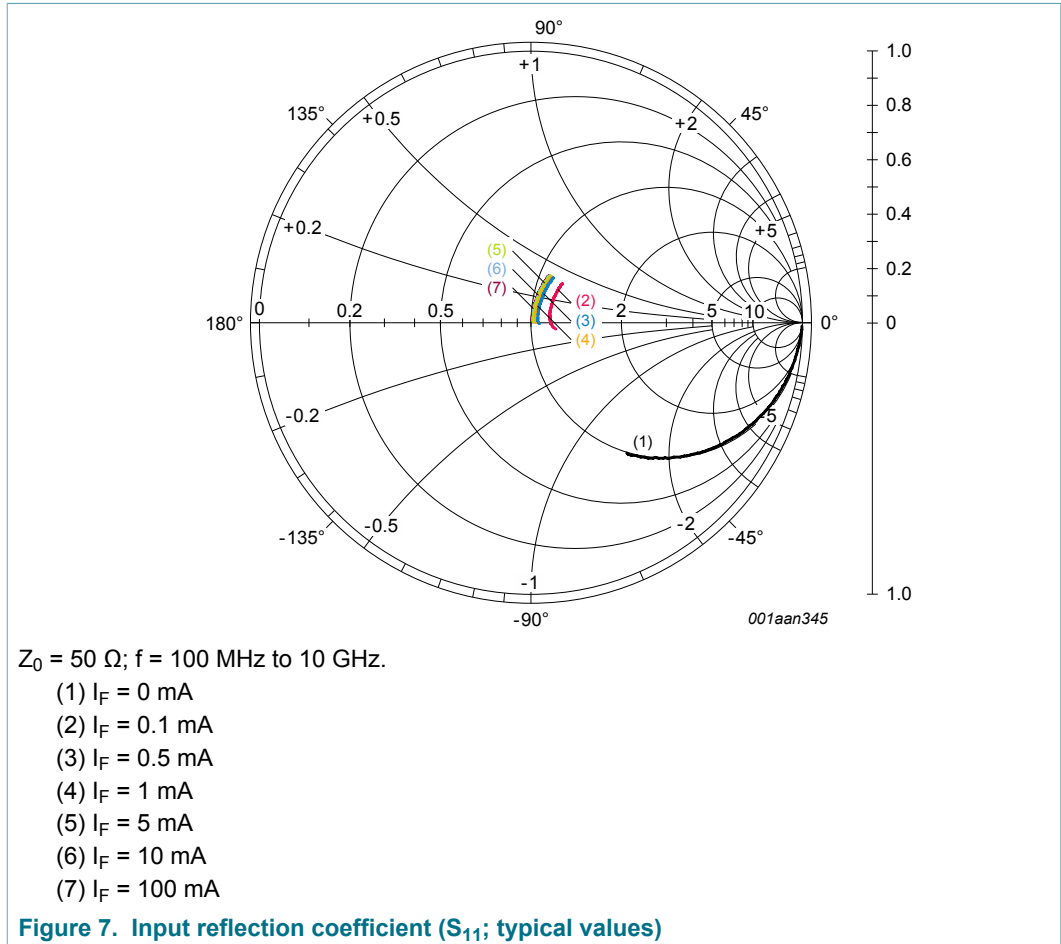
$T_{amb} = 25\text{ }^{\circ}\text{C}$   
 Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer T-network

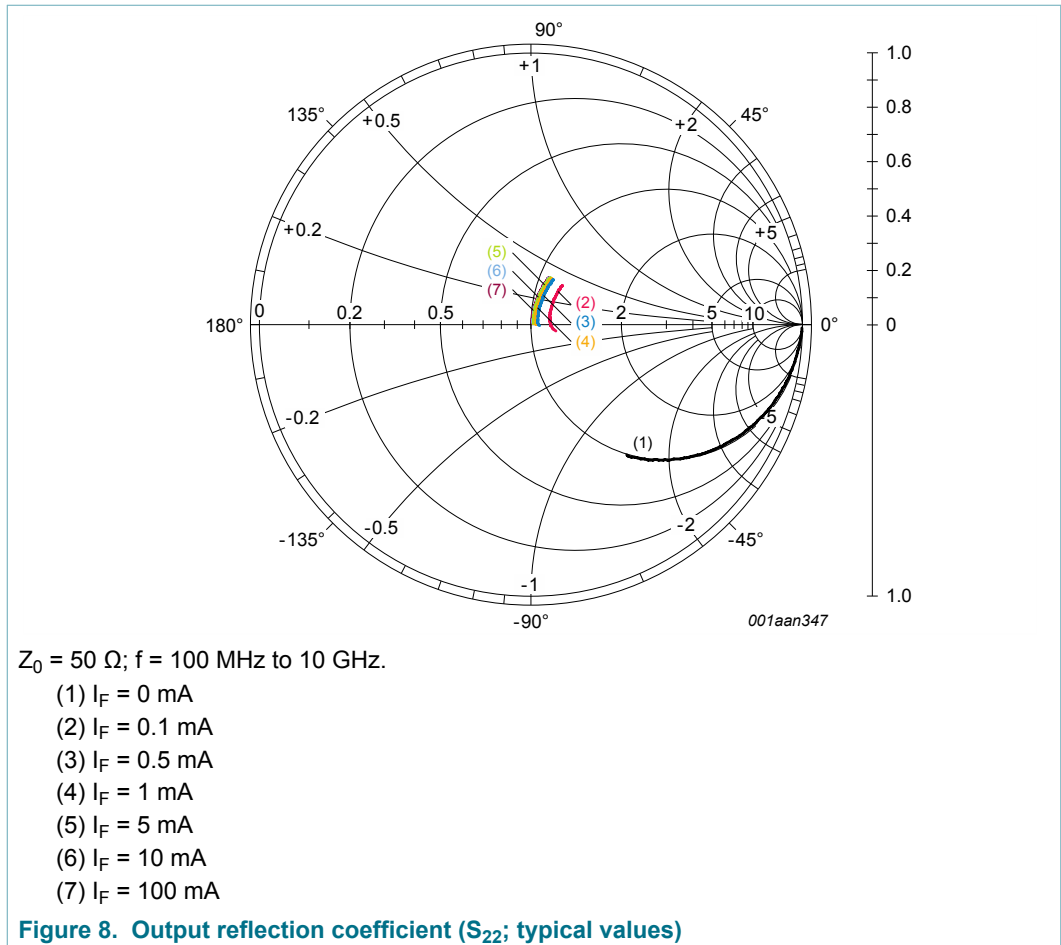
- (1)  $I_F = 100\text{ mA}$
- (2)  $I_F = 10\text{ mA}$
- (3)  $I_F = 1\text{ mA}$
- (4)  $I_F = 0.5\text{ mA}$

**Figure 6. Insertion loss of the diode as a function of frequency (typical values)**

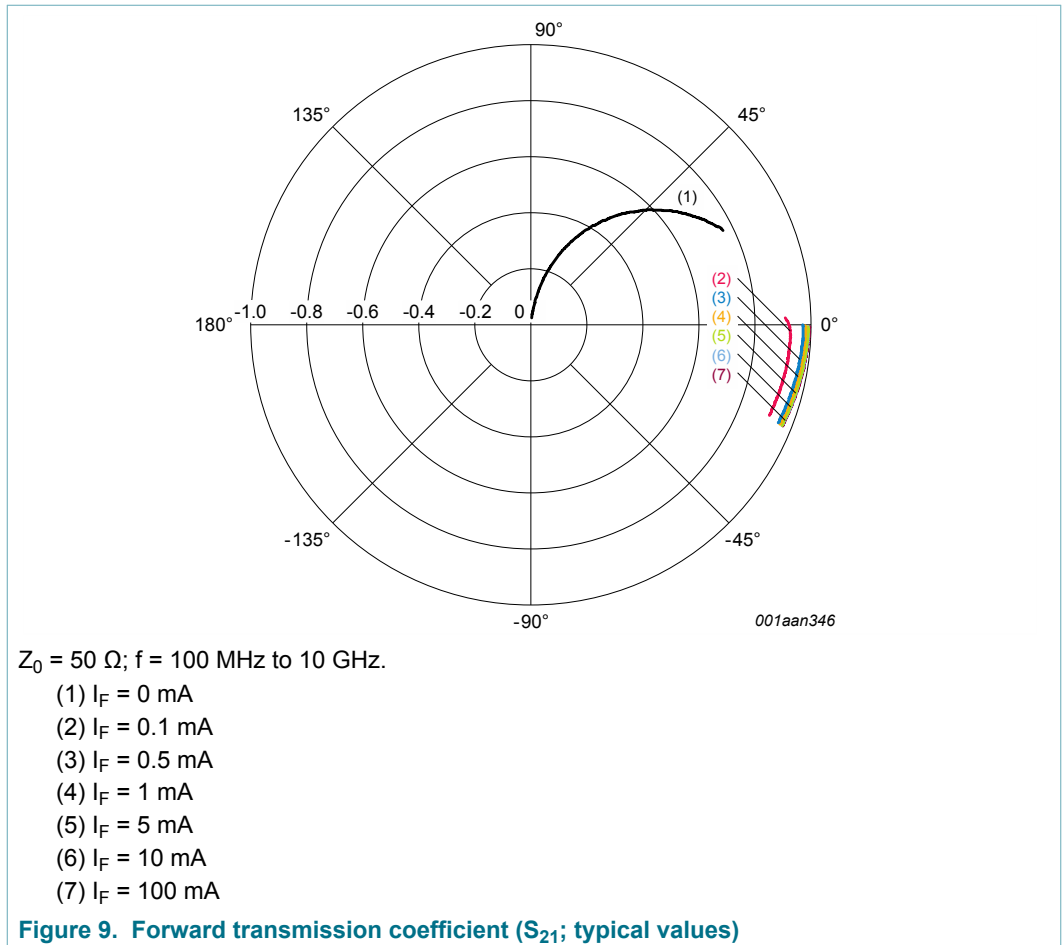
**7.2 S-parameters**

**7.2.1 Diode in series configuration**

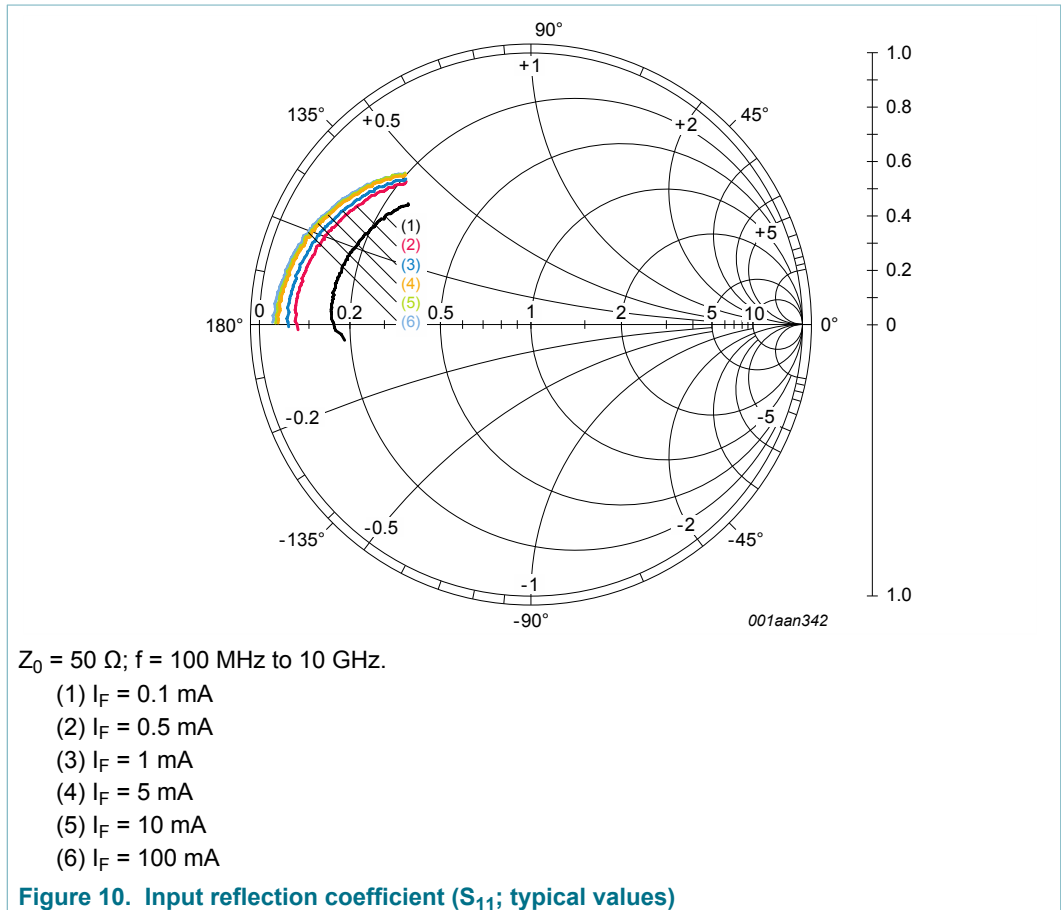


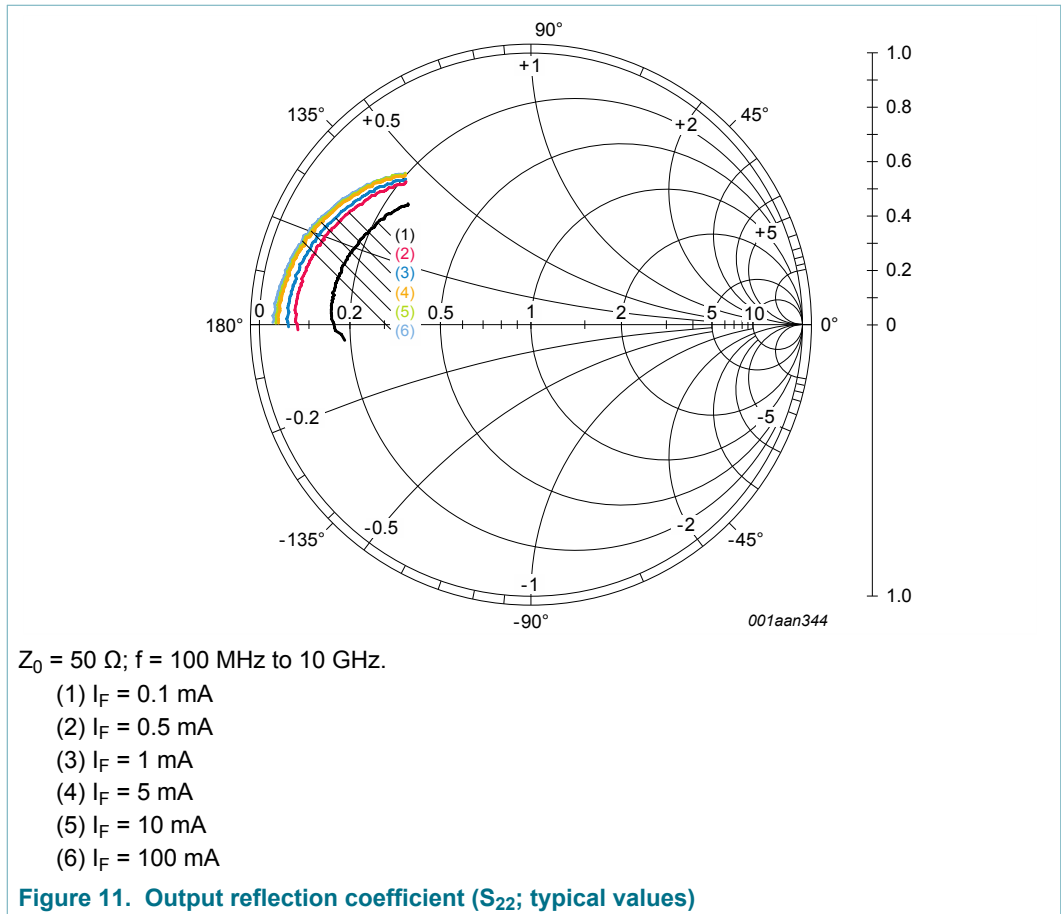


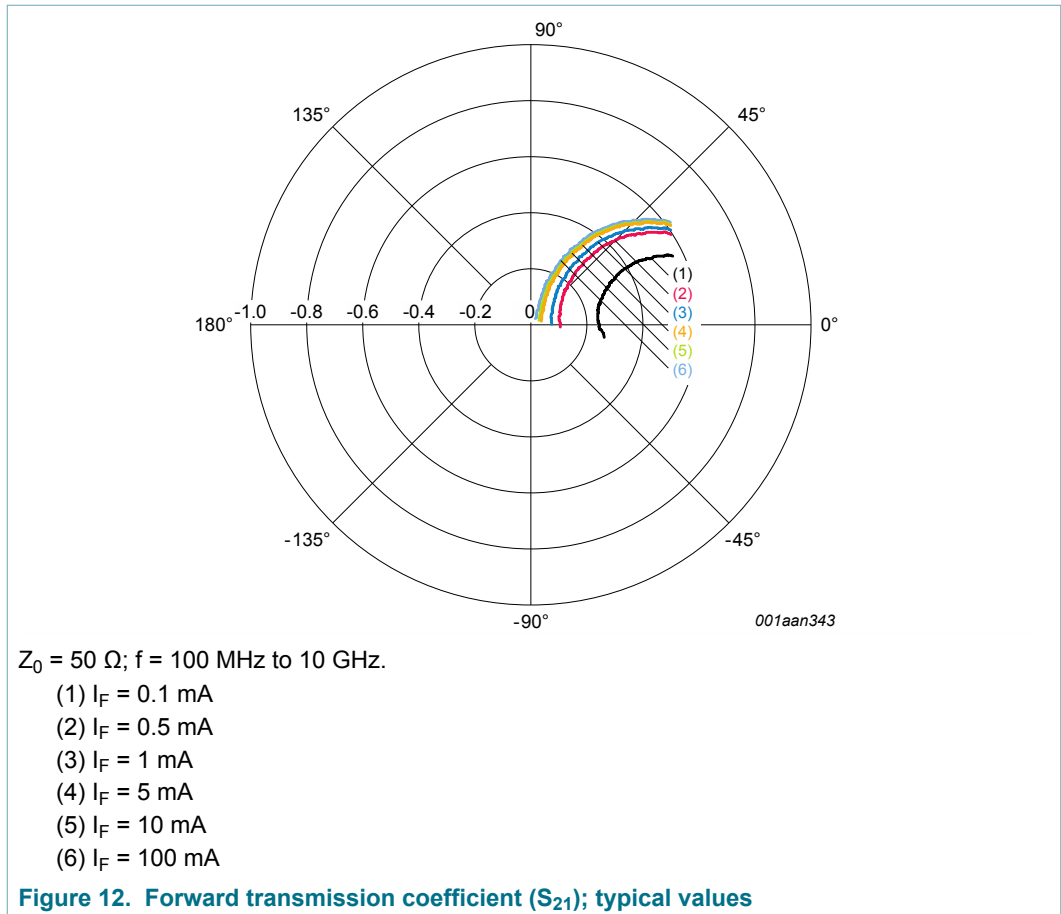




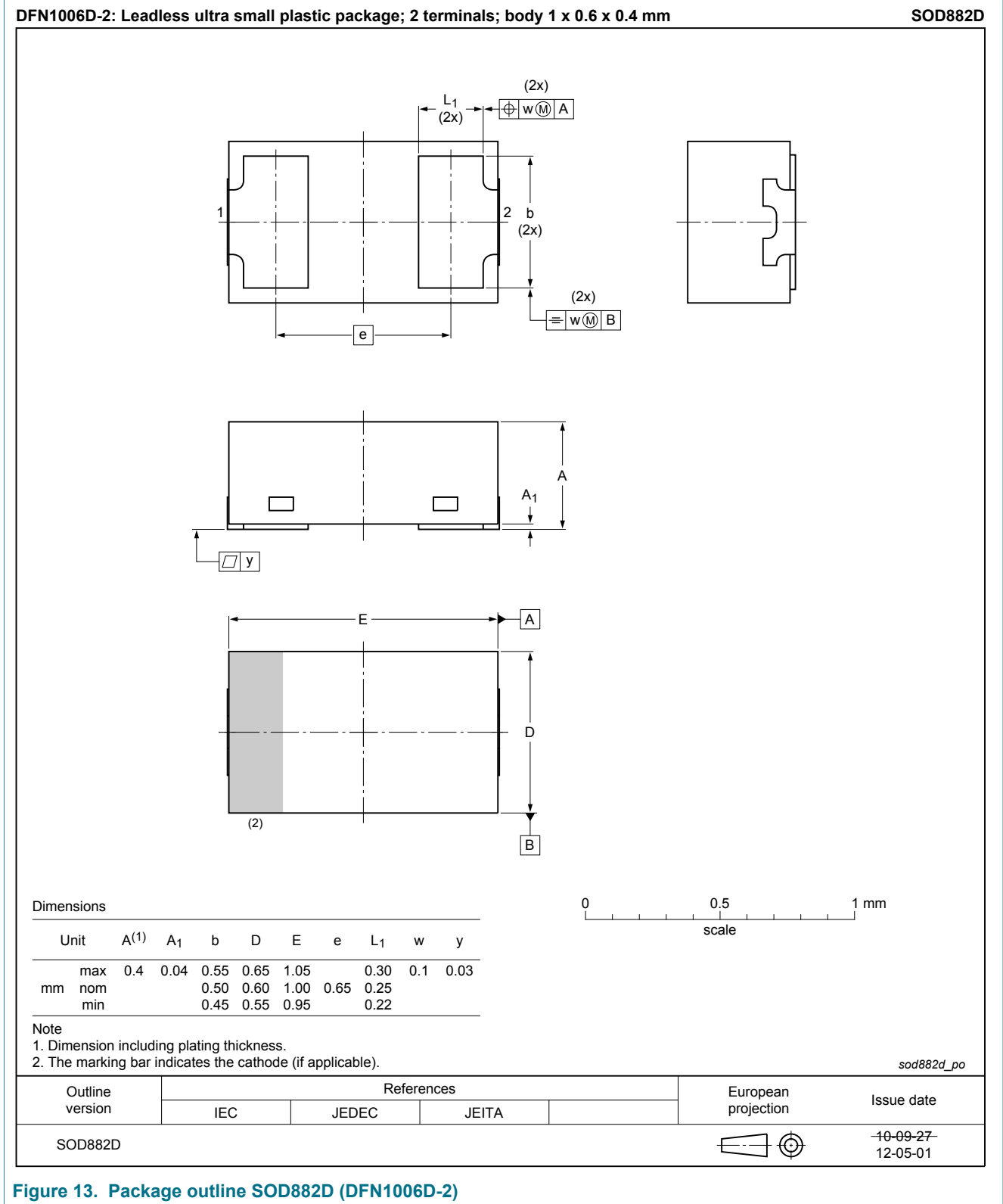
**7.2.2 Diode in parallel configuration**







**8 Package outline**



**Figure 13. Package outline SOD882D (DFN1006D-2)**

## 9 Abbreviations

**Table 7. Abbreviations**

Acronym	Description
PIN	P-type, intrinsic, N-type
SMD	surface-mounted device
RF	radio frequency

## 10 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP55LX v.5	20190212	Product data sheet	-	BAP55LX v.4
Modifications:	<ul style="list-style-type: none"><li>• <a href="#">Section 1.2</a> "Features and benefits" has been updated.</li><li>• The "Legal information" pages have been updated.</li></ul>			
BAP55LX v.4	20130806	Product data sheet	-	BAP55LX v.3
BAP55LX v.3	20110113	Product data sheet	-	BAP55LX v.2
BAP55LX v.2	20101216	Product data sheet	-	BAP55LX v.1
BAP55LX v.1	20070730	Product data sheet	-	-

## 11 Legal information

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 11.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 11.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors. In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without

notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Suitability for use in automotive applications** — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected



to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

## 11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## Contents

<b>1</b>	<b>Product profile</b> .....	<b>1</b>
1.1	General description .....	1
1.2	Features and benefits .....	1
1.3	Applications .....	1
<b>2</b>	<b>Pinning information</b> .....	<b>2</b>
<b>3</b>	<b>Ordering information</b> .....	<b>2</b>
<b>4</b>	<b>Marking</b> .....	<b>2</b>
4.1	Binary marking code description .....	2
<b>5</b>	<b>Limiting values</b> .....	<b>3</b>
<b>6</b>	<b>Thermal characteristics</b> .....	<b>3</b>
<b>7</b>	<b>Characteristics</b> .....	<b>4</b>
7.1	Graphical data .....	5
7.2	S-parameters .....	7
7.2.1	Diode in series configuration .....	7
7.2.2	Diode in parallel configuration .....	10
<b>8</b>	<b>Package outline</b> .....	<b>13</b>
<b>9</b>	<b>Abbreviations</b> .....	<b>14</b>
<b>10</b>	<b>Revision history</b> .....	<b>15</b>
<b>11</b>	<b>Legal information</b> .....	<b>16</b>

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2019.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 12 February 2019  
Document identifier: BAP55LX

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [PIN Diodes](#) category:*

*Click to view products by [NXP](#) manufacturer:*

Other Similar products are found below :

[MA45471](#) [MA4SPS502](#) [APD2220-000](#) [APD0810-000](#) [MA4GP907](#) [MA4L032-186](#) [MA4L401-30](#) [MA4P606-258](#) [MA4P7435NM-1091T](#)  
[MA4PK2000](#) [MA4PK2001](#) [MA4PK2004](#) [MADP-007167-12250T](#) [MADP-030025-13140P](#) [MA4PBL027](#) [MA4AGFCP910](#) [MA4P7101F-1072T](#) [MA4L022-30](#) [MA47047-54](#) [BAR 89-02LRH E6327](#) [UM7108B](#) [UM9701](#) [1SV308,L3F](#) [UM9301SM](#) [5082-3077](#) [GC4723-42](#)  
[MA4L011-1088](#) [MSW2001-200](#) [SMP1321-000](#) [M17X1008](#) [UM4010SM](#) [UM6002B](#) [UM7006A](#) [UM7006B](#) [UM7108C](#) [GC4742-42](#) [MADP-000015-000030](#) [MGPN1503-C01A](#) [UMX512](#) [LXP1000-23-2](#) [LXP1004-23-2](#) [MPP4201-206](#) [LXP1002-23-0](#) [LXP1004-23-0](#) [MPP4202-206](#)  
[MPP4205-206](#) [SMP1321-011LF](#) [MA4L021-1056](#) [MSW2031-203](#) [MLP7120-11](#)